Application Serial No.: 10/646,409

Attorney Docket No .: SP03-108

- b) Amendments to the Claims
- 1. (Currently Amended) A process for making a hard pellicle for a photomask, comprising the following steps:
 - providing a substrate having a substantially flat surface; (i)
- depositing an intermediate layer comprising an amorphous silicon layer on top of (ii) the substantially flat surface of the substrate;
- depositing a pellicle layer having a first surface and a second surface on the surface of the intermediate layer, with the first surface bonding to the surface of the intermediate layer, and the second surface opposite to the first surface;
 - bonding a pellicle mount frame to the second surface of the pellicle layer; and (iv)
- separating the pellicle layer and a portion of the intermediate layer from the (v) substrate at a location within by splitting the intermediate layer by heat treatment.
- 2. (Original) A process in accordance with claim 1, wherein the intermediate layer is a single layer consisting essentially of hydrogenated amorphous silicon.
- A process in accordance with claim 1, wherein the intermediate layer is 3. (Original) a multiple-layer system comprising a first layer of hydrogenated amorphous silicon and a second layer which is fluorinated, wherein the first layer and the second layer have direct contact with each other.
- 4. (Original) A process in accordance with claim 3, wherein the second layer is fluorine doped silica or fluorine doped SiN layer.
- 5. (Original) A process in accordance with claim 3, wherein the first layer is deposited first, and the second layer is deposited on top of the first layer thereafter.
- 6. (Original) A process in accordance with claim 3, wherein the second layer is deposited first, and the first layer is deposited on top of the second layer thereafter.
- 7. (Original) A process in accordance with claim 1, wherein the substrate in step (i) is flat sheet glass, a fused silica wafer, a silicon wafer, or a silicon wafer having a thermal oxidization layer.
- 8. (Original) A process in accordance with claim 1, wherein in step (iii), the pellicle layer consists essentially of a material selected from silica, fluorine doped silica, aluminum doped silica, methylated silica, fluorinated and methylated silica, fluorinated aluminum doped silica, CaF2, MgF2, BaF2 and SiC.

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- 9. (Original) A process in accordance with claim 1, wherein in steps (ii) and (iii), the intermediate layer and the pellicle layer are independently deposited via chemical vapor deposition and/or plasma vapor deposition, or sol-gel process.
- 10. (Original) A process in accordance with claim 9, wherein in steps (ii) (iii), the intermediate layer and the pellicle layer are independently deposited via a process selected from plasmas enhanced chemical vapor deposition (PECVD), low pressure chemical vapor deposition (LPCVD), sub-atmospheric chemical vapor deposition (SACVD), ion-assisted e-beam evaporation, non ion-assisted e-beam evaporation and sputtering.
- 11. (Original) A process in accordance with claim 9, wherein in steps (ii) and (iii), the intermediate layer and pellicle layer are deposited via plasma enhanced chemical vapor deposition (PECVD).
- 12. (Original) A process in accordance with claim 1, wherein in step (iv), the bonding between the pellicle layer and the pellicle mount frame is effected by wafer bonding.
- 13. (Original) A process in accordance with claim 12, wherein the bonding is effected by anodic bonding, low-temperature bonding or fusion bonding.
- 14. (Original) A process in accordance with claim 1, wherein in step (iv), the bonding between the pellicle layer and the pellicle mount frame is effected by using frit.
- 15. (Original) A process in accordance with claim 1, wherein in step (iv), the pellicle mount frame consists essentially of a material having substantially the same coefficient of thermal expansion as that of the pellicle layer.
- 16. (Original) A process in accordance with claim 1, wherein in step (iv), the pellicle mount frame consists essentially of silica.
- 17. (Original) A process in accordance with claim 15, wherein the pellicle mount frame is porous and allows for the passage of purging gas used during the lithographic process.
- 18. (Original) A process in accordance with claim 1, wherein the heat treatment used in step (v) for separating the pellicle layer and a portion of the intermediate layer is effected by laser heating.
- 19. (Original) A process in accordance with claim 1, further comprising either a further step (vi) as follows:

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- (vi) removing the residual material from the intermediate layer on top of the first surface of the pellicle layer; or a step (vii) as follows:
- (vii) converting the residual material from the intermediate layer on top of the first surface of the pellicle layer to a material compatible with the pellicle layer.
- 20. (Original) A process in accordance with claim 19, wherein step (vi) is carried out, in which plasma etching is used to remove the residual material from the intermediate layer.
- 21. (Original) A process in accordance with claim 19, wherein step (vii) is carried out, in which thermal oxidation is used to convert the residual material from the intermediate layer to a material compatible with the pellicle layer.
- 22. (Original) A process in accordance with claim 1, further comprising the following step (viii) after step (v):
- (viii) forming an antireflective coating on at least the pellicle surface opposite to the pellicle mount frame.
- 23. (Original) A process in accordance with claim 19, further comprising the following step (viii) after step (vi) or (vii):
- (viii) forming an antireflective coating on at least the pellicle surface opposite to the pellicle mount frame.